mail

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



1. Scope

The present specifications shall apply to Sanken silicon diode, FML-13S.

2. Outline

Туре	Silicon Rectifier Diode			
Structure	Resin Molded	Flammability : UL94V-0 (Equivalent)		
Applications	High Frequency Rectification			

3. Absolute maximum ratings

No.	Item	Symbol	Unit	Rating	Conditions
1	1 Transient Peak Reverse Voltage		V	300	
2	Peak Reverse Voltage	V _{RM}	V	300	
3	Average Forward Current	I _{F(AV)}	А	5	Tc=122°C Sinewave
4	Peak Surge Forward Current	I _{FSM}	А	40	10msec. Half sinewave, one shot
5	I ² t Limiting Value	I ² t	A ² s	8	1msec≤t≤10msec
6	Junction Temperature	T_j	°C	-40~+150	
7	Storage Temperature	T _{stg}	°C	-40~+150	

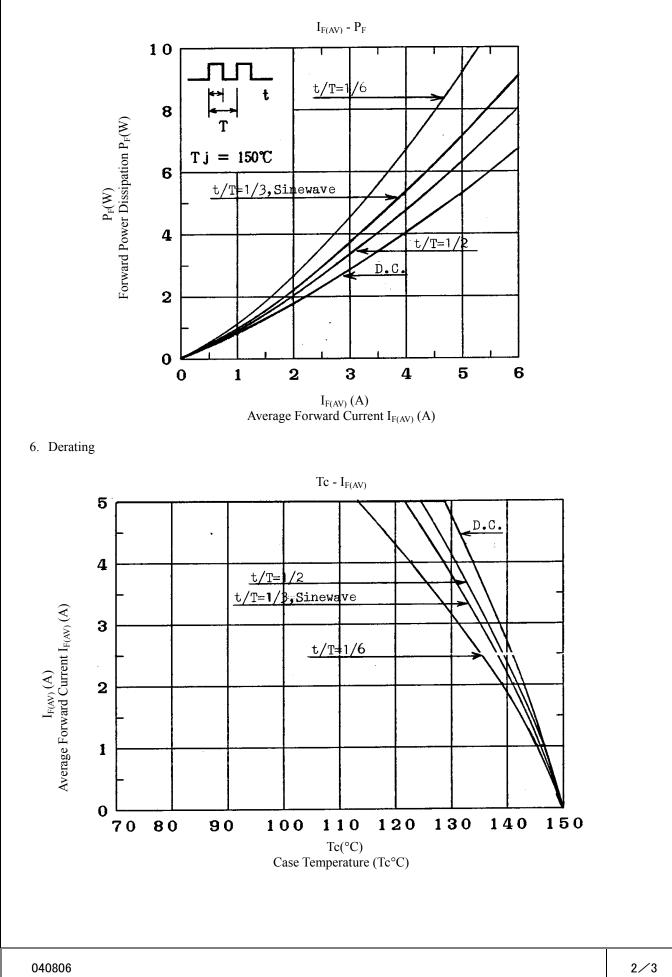
No.1,2,4&5 show ratings per one chip.

4. Electrical characteristics (Ta=25°C, unless otherwise specified)

No	Item	Symbol	Unit	Value	Conditions
1	Forward Voltage Drop	V _F	V	1.3 max.	I _F =2.5A
2	Reverse Leakage Current	I _R	μΑ	50 max.	V _R =V _{RM}
3	Reverse Leakage Current Under High Temperature	H∙I _R	μΑ	250 max.	V _R =V _{RM} , Ta=100°C
4	A Deverse Decessory Time	trr1	ns	50 max.	I _F =I _{RP} =100mA 90% Recovery point, Ta=25°C
	Reverse Recovery Time	trr2	ns	35 max.	I _F =100mA,I _{RP} =200mA 75% Recovery point ,Ta=25°C
5	Thermal Resistance	$R_{th(j-c)}$	°C /W	4.0 max.	Between Junction and case

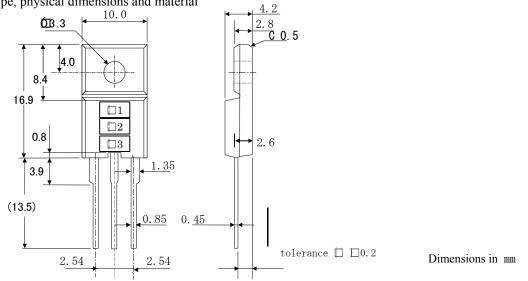
No.1,2,3&4 show characteristics per one chip.

5. Characteristics



7. Package information

7-1 Package type, physical dimensions and material



7-2 Appearance

The body shall be clean and shall not bear any stain, rust or flaw.

7-3 Marking

Type Name	Marking		
	*1 Type Name	*2 Polarity	*3 Lot number
FML-13S	FML13S	_ }+	 1 st letter: Last digit of year 2nd letter: Month From 1 to 9 for Jan. to Sep., O for Oct., N for Nov., D for Dec. 3rd & 4th letter: Day ex. 4806 (Aug. 6, 2004)